Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.260 inches	
Terminal Length:	
1.500 inches	
Overall Diameter:	
0.370 inches	
Electrode Internall	y-electrically Connected To Case:
Collector	
Component Name	And Quantity:
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Dia	meter:
0.100 inches	
Features Provided	
Hermetically sealed	case
Semiconductor Ma	terial:
Silicon all transistor	
Voltage Rating In V	olts Per Characteristic:
45.0 collector to bas	se voltage, dc all transistor
Current Rating Per	Characteristic:
100.00 microampere	es source cutoff current all transistor
Power Rating Per (Characteristic:
300.0 milliwatts sma	Il-signal input power, common-collector all transistor
Transfer Ratio:	
0.8 static forward co transistor	irrent transfer ratio, common-emitter all transistor and 1.0 static forward current transfer ratio, common-emitter a
Special Features:	
All transistor junction	n pattern arrangement: npn
Terminal Type And	Quantity:
3 uninsulated wire le	ad
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	